

High Side Switch with Adjustable Current Limit and Diagnostic Features



ON Semiconductor®

www.onsemi.com

NCV47722

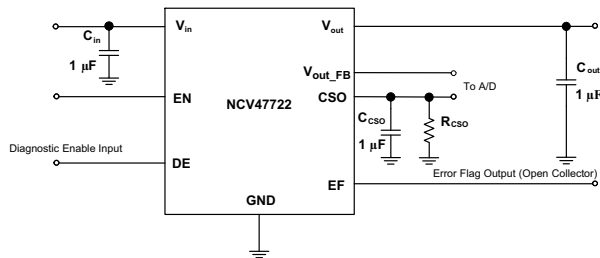
The NCV47722 High Side Switch (HSS) with 250 mA is designed for use in harsh automotive environments. The device has a high peak input voltage tolerance and reverse input voltage, reverse bias, overcurrent and overtemperature protections. The integrated current sense feature (adjustable by resistor connected to CSO pin) provides diagnosis and system protection functionality. The CSO pin output current creates voltage drop across CSO resistor which is proportional to output current. Extended diagnostic features in OFF state are also available and controlled by dedicated input and output pins.

Features

- Output Current: up to 250 mA
- Enable Input (3.3 V Logic Compatible)
- Adjustable Current Limit: up to 350 mA
- Protection Features:
 - ◆ Current Limitation
 - ◆ Thermal Shutdown
 - ◆ Reverse Input Voltage and Reverse Bias Voltage
- Diagnostic Features:
 - ◆ Short To Battery (STB) and Open Load (OL) in OFF State
 - ◆ Internal Components for OFF State Diagnostics
 - ◆ Open Collector Flag Output
 - ◆ Output Voltage Monitoring Output (analog)
- AEC-Q100 Grade 1 Qualified and PPAP Capable
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

Typical Applications

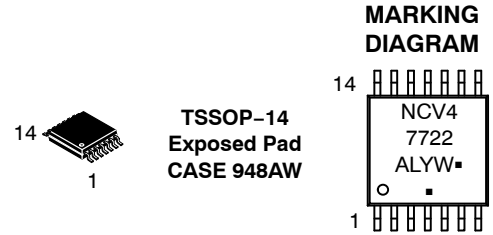
- Audio and Infotainment System
- Active Safety System



*V_{out_FB} is sensed V_{out} output voltage via internal resistor divider

Figure 1. Application Schematic

This document contains information on some products that are still under development. ON Semiconductor reserves the right to change or discontinue these products without notice.



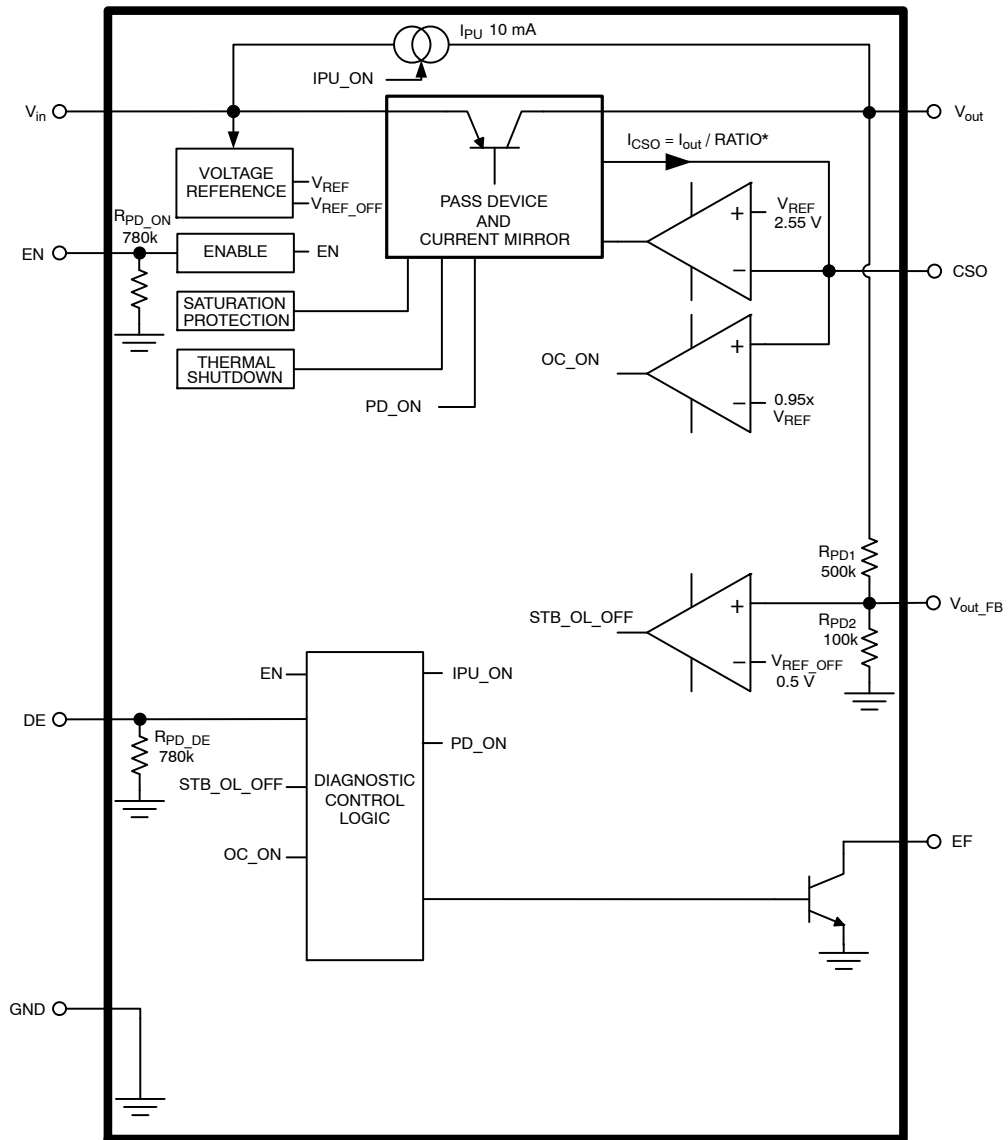
47722 = Specific Device Code
 A = Assembly Location
 L = Wafer Lot
 Y = Year
 W = Work Week
 ▪ = Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 10 of this data sheet.

NCV47722



*) for current value of RATIO see into Electrical Characteristic Table

Figure 2. Simplified Block Diagram

NCV47722

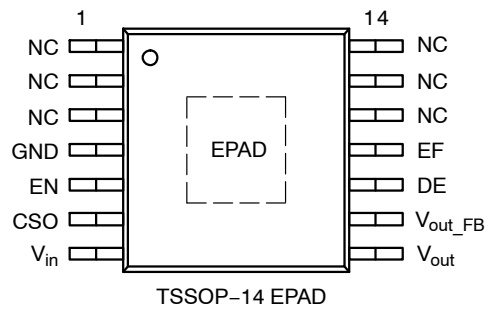


Figure 3. Pin Connections (Top Views)

Table 1. PIN FUNCTION DESCRIPTION

| Pin No. TSSOP-14 EPAD | Pin Name | Description |
|-----------------------------|---------------------|---|
| 1 | NC | Not Connected, not internally bonded. |
| 2 | NC | Not Connected, not internally bonded. |
| 3 | NC | Not Connected, not internally bonded. |
| 4 | GND | Power Supply Ground. |
| 5 | EN | Enable Input; low level disables regulator. (Used also for OFF state diagnostics control. |
| 6 | CSO | Current Sense Output, Current Limit setting and Output Current value information. See Application Section for more details. |
| 7 | V _{in} | Power Supply Input. |
| 8 | V _{out} | Regulated Output Voltage. |
| 9 | V _{out_FB} | Output Voltage Analog Monitoring. See Application Section for more details. |
| 10 | DE | Diagnostic Enable Input. |
| 11 | EF | Error Flag (Open Collector) Output. Active Low. |
| 12 | NC | Not Connected, not internally bonded. |
| 13 | NC | Not Connected, not internally bonded. |
| 14 | NC | Not Connected, not internally bonded. |
| EPAD | EPAD | Exposed Pad is connected to Ground. Connect to GND plane on PCB. |

Table 2. MAXIMUM RATINGS

| Rating | Symbol | Min | Max | Unit |
|--|--------------------------|------|-----|------|
| Input Voltage DC | V_{in} | -42 | 45 | V |
| Input Voltage (Note 1) Load Dump – Suppressed | U_{S*} | - | 60 | V |
| Enable Input Voltage | V_{EN} | -42 | 45 | V |
| Output Voltage Monitoring | V_{out_FB} | -0.3 | 10 | V |
| CSO Voltage | V_{CSO} | -0.3 | 7 | V |
| DE, CS and EF Voltages | V_{DE}, V_{CS}, V_{EF} | -0.3 | 7 | V |
| Output Voltage | V_{out} | -1 | 40 | V |
| Junction Temperature | T_J | -40 | 150 | °C |
| Storage Temperature | T_{STG} | -55 | 150 | °C |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Load Dump Test B (with centralized load dump suppression) according to ISO16750-2 standard. Guaranteed by design. Not tested in production. Passed Class A according to ISO16750-1.

Table 3. ESD CAPABILITY (Note 2)

| Rating | Symbol | Min | Max | Unit |
|----------------------------------|-------------|-----|-----|------|
| ESD Capability, Human Body Model | ESD_{HBM} | -2 | 2 | kV |

2. This device series incorporates ESD protection and is tested by the following methods:
 ESD Human Body Model tested per AEC-Q100-002 (JS-001-2010)
 Field Induced Charge Device Model ESD characterization is not performed on plastic molded packages with body sizes < 50 mm² due to the inability of a small package body to acquire and retain enough charge to meet the minimum CDM discharge current waveform characteristic defined in JEDEC JS-002-2014.

Table 4. LEAD SOLDERING TEMPERATURE AND MSL (Note 3)

| Rating | Symbol | Min | Max | Unit |
|----------------------------|--------|-----|-----|------|
| Moisture Sensitivity Level | MSL | 1 | | - |

3. For more information, please refer to our Soldering and Mounting Techniques Reference Manual, SOLDERRM/D

THERMAL CHARACTERISTICS (Note 4)

| Rating | Symbol | Value | Unit |
|--|----------------------------------|--------------|------|
| Thermal Characteristics (single layer PCB) Thermal Resistance, Junction-to-Air (Note 5) Thermal Reference, Junction-to-Lead (Note 5) | $R_{\theta JA}$ $R_{\psi JL}$ | 62.6 23.7 | °C/W |
| Thermal Characteristics (4 layers PCB) Thermal Resistance, Junction-to-Air (Note 5) Thermal Reference, Junction-to-Lead (Note 5) | $R_{\theta JA}$ $R_{\psi JL}$ | 44.1 16.8 | °C/W |

4. Refer to ELECTRICAL CHARACTERISTICS and APPLICATION INFORMATION for Safe Operating Area.
5. Values based on copper area of 645 mm² (or 1 in²) of 1 oz copper thickness and FR4 PCB substrate. Single layer – according to JEDEC51.3, 4 layers – according to JEDEC51.7

Table 5. RECOMMENDED OPERATING RANGES

| Rating | Symbol | Min | Max | Unit |
|--------------------------------------|-----------|-----|-----|------|
| Input Voltage (Note 6) | V_{in} | 4.4 | 40 | V |
| Output Current Limit (Note 7) | I_{LIM} | 10 | 350 | mA |
| Junction Temperature | T_J | -40 | 150 | °C |
| Current Sense Output (CSO) Capacitor | C_{CSO} | 1 | 4.7 | μF |

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

6. Minimum $V_{in} = 4.4$ V or ($V_{out} + 0.5$ V), whichever is higher.
7. Corresponding R_{CSO} is in range from 76.5 kΩ down to 2185 Ω.

NCV47722

Table 6. ELECTRICAL CHARACTERISTICS $V_{in} = 13.5\text{ V}$, $V_{EN} = 3.3\text{ V}$, $R_{CSO} = 0\ \Omega$, $C_{CSO} = 1\ \mu\text{F}$, $C_{in} = 1\ \mu\text{F}$, $C_{out} = 1\ \mu\text{F}$, Min and Max values are valid for temperature range $-40^{\circ}\text{C} \leq T_J \leq +150^{\circ}\text{C}$ unless noted otherwise and are guaranteed by test, design or statistical correlation. Typical values are referenced to $T_J = 25^{\circ}\text{C}$ (Note 8)

| Parameter | Test Conditions | Symbol | Min | Typ | Max | Unit |
|-----------|-----------------|--------|-----|-----|-----|------|
|-----------|-----------------|--------|-----|-----|-----|------|

OUTPUTS

| | | | | | | |
|--------------------------------------|--|--------------|---|------------|------------|----|
| Input to Output Differential Voltage | $V_{in} = 8\text{ V to }18\text{ V}$ $I_{out} = 200\text{ mA}$ $I_{out} = 250\text{ mA}$ | V_{in-out} | - | 200 225 | 350 400 | mV |
|--------------------------------------|--|--------------|---|------------|------------|----|

CURRENT LIMIT PROTECTION

| | | | | | | |
|---------------|---------------------------------|-----------|-----|---|---|----|
| Current Limit | $V_{out} = V_{in} - 1\text{ V}$ | I_{LIM} | 350 | - | - | mA |
|---------------|---------------------------------|-----------|-----|---|---|----|

DISABLE AND QUIESCENT CURRENTS

| | | | | | | |
|---|---|-----------|---|-------|-----|---------------|
| Disable Current | $V_{EN} = 0\text{ V}$ | I_{DIS} | - | 0.002 | 10 | μA |
| Quiescent Current, $I_q = I_{in} - I_{out}$ | $I_{out} = 500\ \mu\text{A}$, $V_{in} = 8\text{ V to }18\text{ V}$ | I_q | - | 0.5 | 1.3 | mA |
| Quiescent Current, $I_q = I_{in} - I_{out}$ | $I_{out} = 200\text{ mA}$, $V_{in} = 8\text{ V to }18\text{ V}$ | I_q | - | 8 | 19 | mA |
| Quiescent Current, $I_q = I_{in} - I_{out}$ | $I_{out} = 250\text{ mA}$, $V_{in} = 8\text{ V to }18\text{ V}$ | I_q | - | 11 | 25 | mA |

ENABLE

| | | | | | | |
|--|---|--------------|-----------|------------|-----------|---------------|
| Enable Input Threshold Voltage Logic Low (OFF) Logic High (ON) | $V_{out} \leq 0.1\text{ V}$ $V_{out} \geq V_{in} - 1\text{ V}$ | $V_{th(EN)}$ | 0.99 - | 1.8 1.9 | - 2.31 | V |
| Enable Input Current | $V_{EN} = 3.3\text{ V}$ | I_{EN} | 2 | 9 | 20 | μA |
| Turn On Time from Enable ON to $V_{out} = V_{in} - 1\text{ V}$ | $I_{out} = 100\text{ mA}$ | t_{on} | - | 25 | - | μs |

OUTPUT CURRENT SENSE

| | | | | | | |
|-------------------------------------|---|-------------------|----------------|------|----------------|---------------|
| CSO Voltage Level at Current Limit | $V_{out} = V_{in} - 1\text{ V}$ $R_{CSO} = 3.3\text{ k}\Omega$ | V_{CSO_Ilim} | 2.448 (-4%) | 2.55 | 2.652 (+4%) | V |
| CSO Transient Voltage Level | $C_{CSO} = 4.7\ \mu\text{F}$, $R_{CSO} = 3.3\text{ k}\Omega$ I_{out} pulse from 10 mA to 350 mA, $t_r = 1\ \mu\text{s}$ | V_{CSO} | - | - | 3.3 | V |
| Output Current to CSO Current Ratio | $V_{CSO} = 2\text{ V}$, $I_{out} = 10\text{ mA to }50\text{ mA}$ $V_{in} = 8\text{ V to }18\text{ V}$, $-40^{\circ}\text{C} \leq T_J \leq +150^{\circ}\text{C}$ | I_{out}/I_{CSO} | - (-15%) | 265 | - (+15%) | - |
| Output Current to CSO Current Ratio | $V_{CSO} = 2\text{ V}$, $I_{out} = 50\text{ mA to }350\text{ mA}$ $V_{in} = 8\text{ V to }18\text{ V}$, $-40^{\circ}\text{C} \leq T_J \leq +150^{\circ}\text{C}$ | I_{out}/I_{CSO} | - (-5%) | 285 | - (+5%) | - |
| CSO Current at no Load Current | $V_{CSO} = 0\text{ V}$, $I_{out} = 0\text{ mA}$ | I_{CSO_off} | - | - | 15 | μA |

DIAGNOSTICS

| | | | | | | |
|--|---|---------------------|-----------|------------|-----------|----------------------|
| Overcurrent Voltage Level Threshold | $V_{out} = V_{in} - 1\text{ V}$ $R_{CSO} = 3.3\text{ k}\Omega$ | V_{OC} | 92 | 95 | 98 | % of V_{CSO_Ilim} |
| Short To Battery (STB) Voltage Threshold in OFF state | $V_{in} = 4.4\text{ V to }18\text{ V}$, $I_{out} = 0\text{ mA}$ | V_{STB} | 2 | 3 | 4 | V |
| Open Load (OL) Current Threshold in OFF state | $V_{in} = 4.4\text{ V to }18\text{ V}$ | I_{OL} | 5 | 10 | 25 | mA |
| Output Voltage to Output Feedback Voltage Ratio | $V_{in} = 4.4\text{ V to }18\text{ V}$ | V_{out}/V_{outFB} | 5.7 | 6 | 6.3 | - |
| Diagnostics Enable Threshold Voltage Logic Low (OFF) Logic High (ON) | | $V_{th(DE)}$ | 0.99 - | 1.8 1.9 | - 2.31 | V |
| Error Flag Low Voltage | $I_{EF} = -1\text{ mA}$ | V_{EF_Low} | - | 0.04 | 0.4 | V |

THERMAL SHUTDOWN

| | | | | | | |
|---------------------------------------|--------------------------|----------|-----|-----|-----|--------------------|
| Thermal Shutdown Temperature (Note 9) | $I_{out} = 90\text{ mA}$ | T_{SD} | 150 | 175 | 195 | $^{\circ}\text{C}$ |
|---------------------------------------|--------------------------|----------|-----|-----|-----|--------------------|

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

8. Performance guaranteed over the indicated operating temperature range by design and/or characterization tested at $T_A \approx T_J$. Low duty cycle pulse techniques are used during testing to maintain the junction temperature as close to ambient as possible.
9. Values based on design and/or characterization.

TYPICAL CHARACTERISTICS

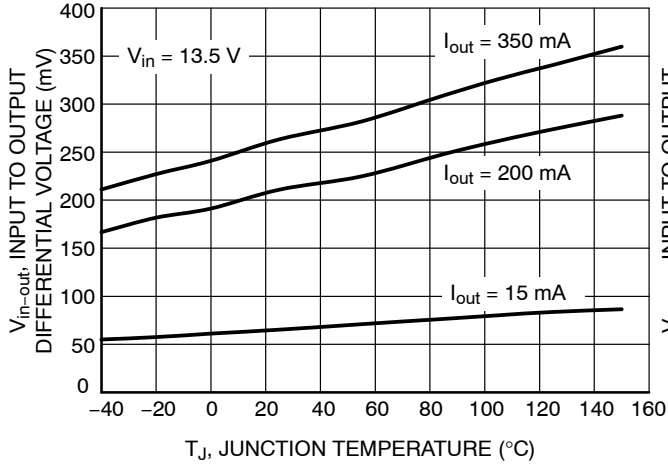


Figure 4. Input to Output Differential Voltage vs. Temperature

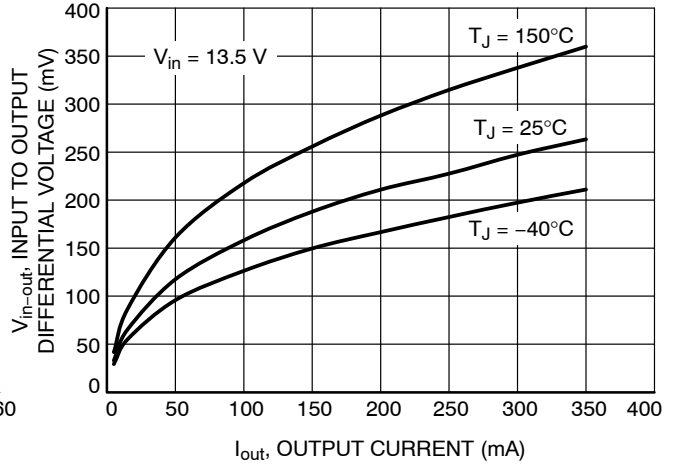


Figure 5. Input to Output Differential Voltage vs. Output Current

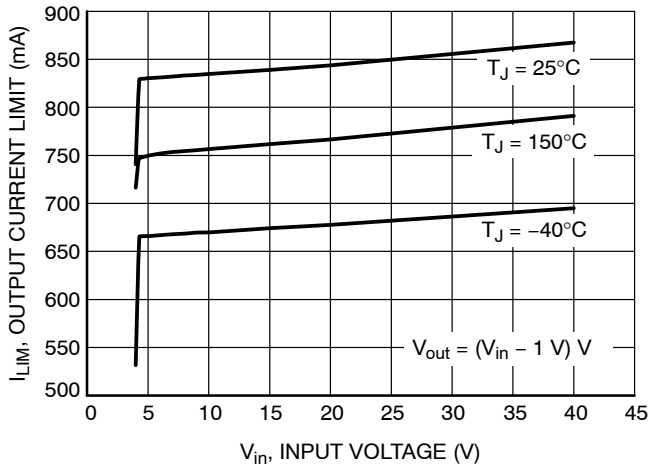


Figure 6. Output Current Limit vs. Input Voltage

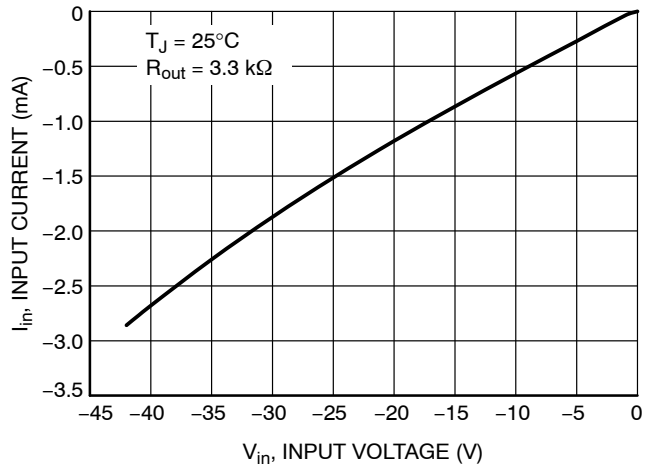


Figure 7. Input Current vs. Input Voltage (Reverse Input Voltage)

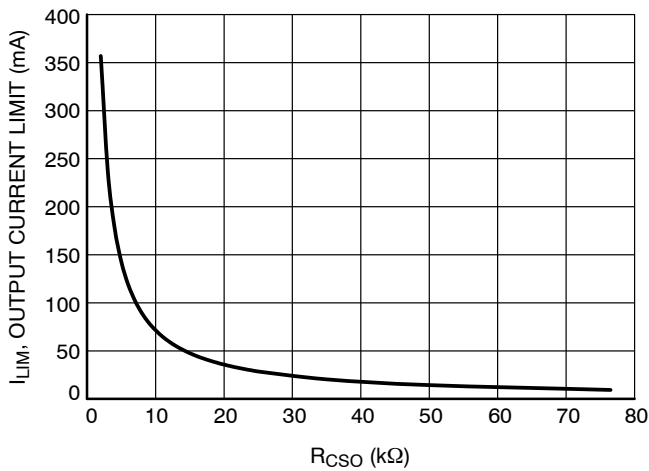


Figure 8. Output Current Limit vs. R_{CSO}

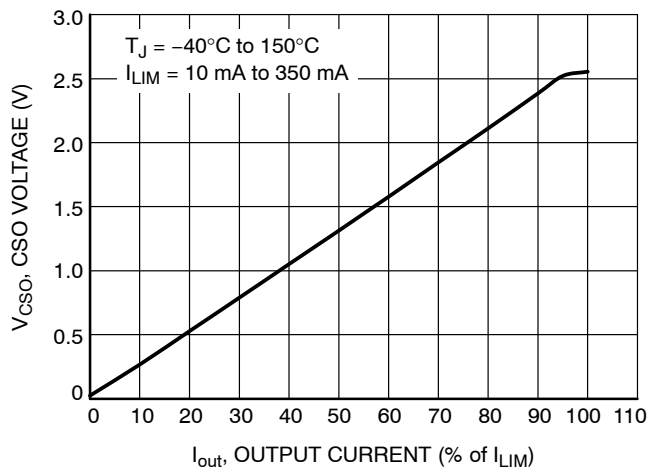


Figure 9. CSO Voltage vs. Output Current (% of I_{LIM})

TYPICAL CHARACTERISTICS

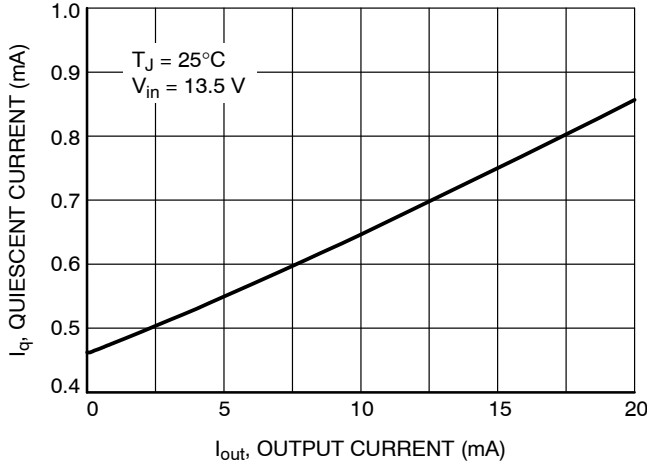


Figure 10. Quiescent Current vs. Output Current (Low Load)

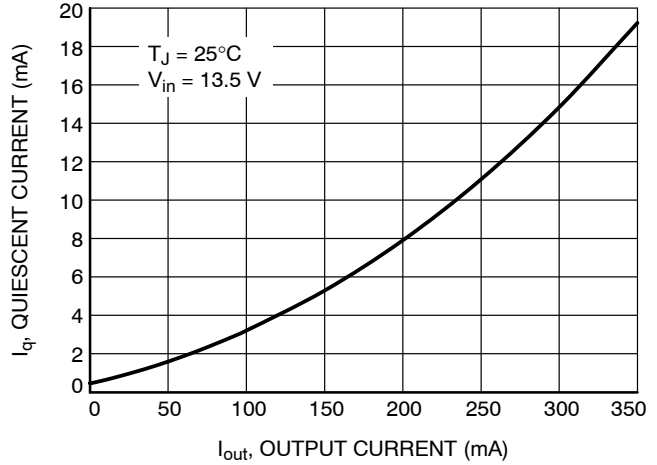


Figure 11. Quiescent Current vs. Output Current (High Load)

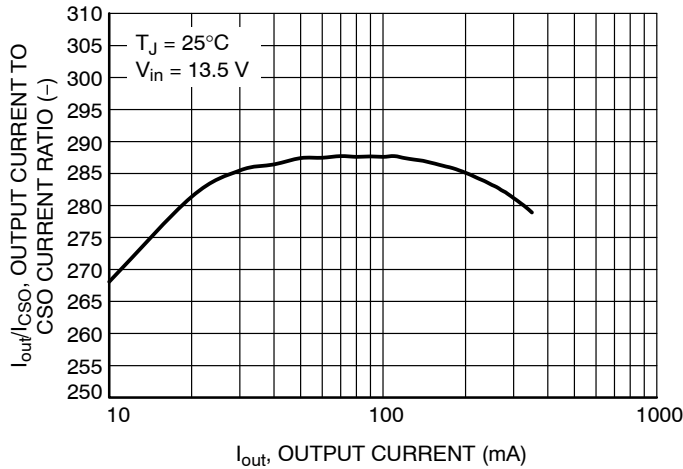


Figure 12. Output Current to CSO Current Ratio vs. Output Current

DEFINITIONS

General

All measurements are performed using short pulse low duty cycle techniques to maintain junction temperature as close as possible to ambient temperature.

Input to Output Differential Voltage

The Input to Output Differential Voltage parameter is defined for specific output current values and specified over Temperature range.

Quiescent and Disable Currents

Quiescent Current (I_q) is the difference between the input current (measured through the LDO input pin) and the output load current. If Enable pin is set to LOW the regulator reduces its internal bias and shuts off the output, this term is called the disable current (I_{DIS}).

Current Limit

Current Limit is value of output current by which output voltage drops 1 V below input supply voltage level.

Thermal Protection

Internal thermal shutdown circuitry is provided to protect the integrated circuit in the event that the maximum junction temperature is exceeded. When activated at typically 175°C, the regulator turns off. This feature is provided to prevent failures from accidental overheating.

Maximum Package Power Dissipation

The power dissipation level is maximum allowed power dissipation for particular package or power dissipation at which the junction temperature reaches its maximum operating value, whichever is lower.

APPLICATIONS INFORMATION

Circuit Description

The NCV47722 is an integrated High Side Switch (HSS) with output current capability up to 250 mA to output. It is enabled with an input to the enable pin. The integrated current sense feature provides diagnosis and system protection functionality. The current limit of the device is adjustable by resistor connected to CSO pin. Voltage on CSO pin is proportional to output current. The HSS is protected by both current limit and thermal shutdown. Thermal shutdown occurs above 150°C to protect the IC during overloads and extreme ambient temperatures.

Enable Input

The enable pin is used to turn the regulator on or off. By holding the pin down to a voltage less than 0.99 V, the output of the regulator will be turned off. When the voltage on the enable pin is greater than 2.31 V, the output of the regulator will be enabled to power its output to the regulated output voltage. The enable pin may be connected directly to the input pin to give constant enable to the output regulator.

Setting the Output Current Limit

The output current limit can be set up to 350 mA by external resistor R_{CSO} (see Figure 1). Capacitor C_{CSO} of 1 μF in parallel with R_{CSO} is required for stability of current limit control circuitry (see Figure 1).

$$V_{CSO} = I_{out} \left(R_{CSO} \times \frac{1}{RATIO} \right) \quad (eq. 1)$$

$$I_{LIM} = RATIO \times \frac{2.55}{R_{CSO}} \quad (eq. 2)$$

$$R_{CSO} = RATIO \times \frac{2.55}{I_{LIM}} \quad (eq. 3)$$

where

- R_{CSO} – current limit setting resistor
- V_{CSO} - voltage at CSO pin proportional to I_{out}
- I_{LIM} – current limit value
- I_{out} – output current actual value
- RATIO – typical value of Output Current to CSO Current Ratio for particular output current range

CSO pin provides information about output current actual value. The CSO voltage is proportional to output current according to Equation 1.

Once output current reaches its limit value (I_{LIM}) set by external resistor R_{CSO} than voltage at CSO pin is typically 2.55 V. Calculations of I_{LIM} or R_{CSO} values can be done using Equation 2 and Equation 3, respectively. Minimum and maximum value of Output Current Limit can be calculated according to Equations 4 and 5.

$$I_{LIM_min} = RATIO_{min} \times \frac{V_{CSO_min}}{R_{CSO_max}} \quad (eq. 4)$$

$$I_{LIM_max} = RATIO_{max} \times \frac{V_{CSO_max}}{R_{CSO_min}} \quad (eq. 5)$$

where

RATIO_{min} – minimum value of Output Current to CSO Current Ratio from electrical characteristics table and particular output current range

RATIO_{max} – maximum value of Output Current to CSO Current Ratio from electrical characteristics table and particular output current range

V_{CSO_min} - minimum value of CSO Voltage Level at Current Limit from electrical characteristics table

V_{CSO_max} - maximum value of CSO Voltage Level at Current Limit from electrical characteristics table

R_{CSO_min} – minimum value of R_{CSO} with respect its accuracy

R_{CSO_max} – maximum value of R_{CSO} with respect its accuracy

Designers should consider the tolerance of R_{CSO} during the design phase.

Diagnostic in OFF State

The NCV47722 contains also circuitry for OFF state diagnostics for Short to Battery (STB) and Open Load (OL). There are internal current source and Pull Down resistors which provide additional cost savings for overall application by excluding external components and their assembly cost and saving PCB space and safe control IOs of a Microcontroller Unit (MCU).

Simplified functional schematic and truth table is shown in Figure 13 and related flowchart in Figure 14.

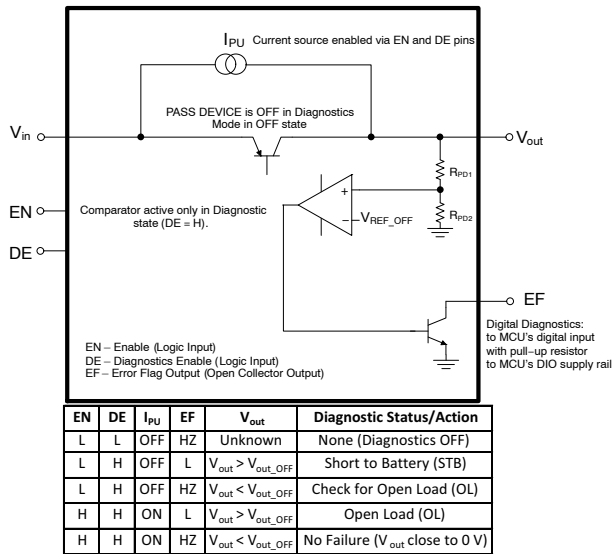


Figure 13. Simplified Functional Diagram of OFF State Diagnostics (STB and OL)

For diagnostics in OFF state the input DE pin has to be put logic high. Logic level on EN pin determines which failure (STB or OL) is diagnosed. For detailed information see Diagnostic Truth Table 7.

Diagnostic in ON State

Diagnostic in ON State provides information about Overcurrent or Short to Ground failures, during which the EF output is in logic low state. For detailed information see Diagnostic Features Truth Table 7.

Table 7. DIAGNOSTIC FEATURES TRUTH TABLE

| Operational Status | EN | DE | Output Voltage (V _{out}) | Diagnostic Output (CSO) | Error Flag (EF) |
|--------------------|----|----|--|--|-----------------|
| Disabled | L | L | Low (~0 V) | Low (~0 V) | HZ |
| Short to Battery | L | H | High (V _{out} ~ V _{in}) | Low (~0 V) | L (Note 10) |
| Open Load (OFF) | H | H | High (V _{out} ~ V _{in}) | Low (~0 V) | L (Note 11) |
| Normal (OFF) | H | H | Low (~0 V) | Low (~0 V) | HZ (Note 11) |
| Open Load (ON) | H | L | High (V _{out} ~ V _{in}) | Low (~0 V) | HZ |
| Normal (ON) | H | L | High (V _{out} ~ V _{in}) | Proportional to I _{out} (±5%) (Note 12) | HZ |
| Over Current | H | L | V _{in} - 1 V | High (~2.55 V) | L |
| Short to Ground | H | L | Low (~0 V) | High (~2.55 V) | L |

10. Internal current source disabled (between V_{out} and V_{in}).

11. Internal current source enabled (between V_{out} and V_{in}).

12. Valid for I_{out} = 50 mA to 350 mA. For I_{out} = 10 mA to 50 mA range proportional to I_{out} (±15%).

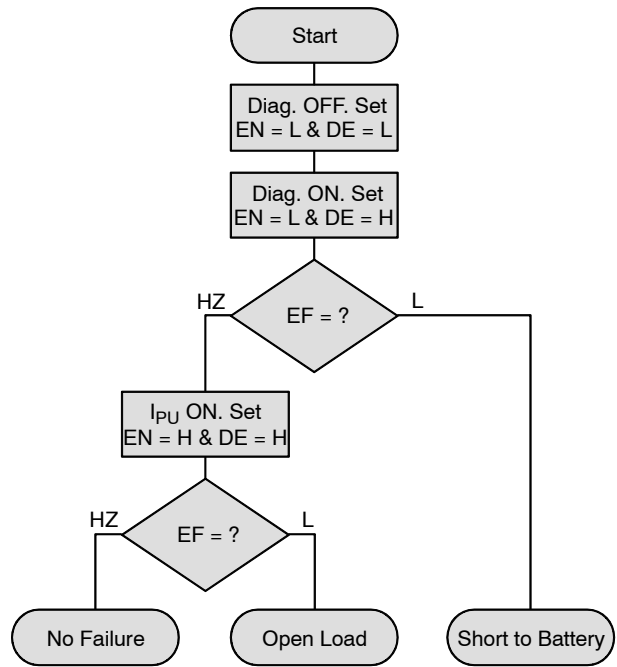


Figure 14. Flowchart for Diagnostics in OFF State

Thermal Considerations

As power in the device increases, it might become necessary to provide some thermal relief. The maximum power dissipation supported by the device is dependent upon board design and layout. Mounting pad configuration on the PCB, the board material, and the ambient temperature affect the rate of junction temperature rise for the part. When the device has good thermal conductivity through the PCB, the junction temperature will be relatively low with high power applications. The maximum dissipation the device can handle is given by:

$$P_{D(MAX)} = \frac{[T_{J(MAX)} - T_A]}{R_{\theta JA}} \quad (\text{eq. 6})$$

Since T_J is not recommended to exceed 150°C, then the device soldered on 645 mm², 1 oz copper area, FR4 can dissipate up to 2 W when the ambient temperature (T_A) is 25°C. See Figure 15 for $R_{\theta JA}$ versus PCB area. The power dissipated by the device can be calculated from the following equations:

$$P_D \approx V_{in}(I_q @ I_{out}) + I_{out}(V_{in} - V_{out}) \quad (\text{eq. 7})$$

or

$$V_{in(MAX)} \approx \frac{P_{D(MAX)} + (V_{out} \times I_{out})}{I_{out} + I_q} \quad (\text{eq. 8})$$

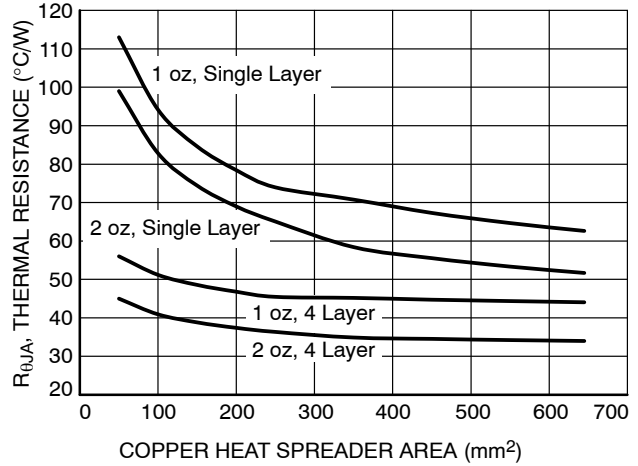


Figure 15. Thermal Resistance vs. PCB Copper Area

Hints

V_{in} and GND printed circuit board traces should be as wide as possible. When the impedance of these traces is high, there is a chance to pick up noise or cause the regulator to malfunction. Place external components, especially the output capacitor, as close as possible to the device and make traces as short as possible.

ORDERING INFORMATION

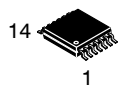
| Device | Marking | Package | Shipping† |
|-----------------|----------------------------|-----------------------------------|--------------------|
| NCV47722PAAJR2G | Line1: NCV4 Line2: 7722 | TSSOP-14 Exposed Pad (Pb-Free) | 2500 / Tape & Reel |

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D

MECHANICAL CASE OUTLINE

PACKAGE DIMENSIONS

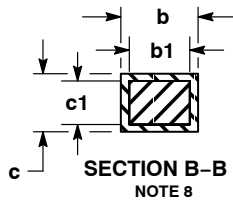
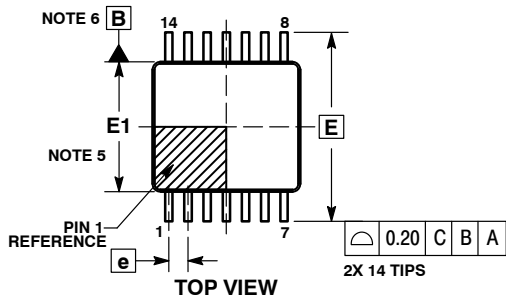
ON Semiconductor®



SCALE 1:1

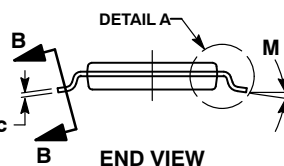
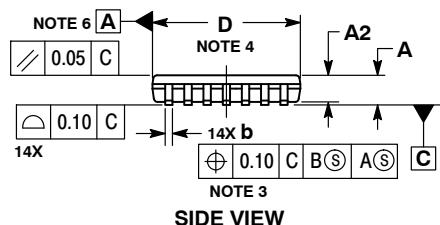
TSSOP-14 EP CASE 948AW ISSUE C

DATE 09 OCT 2012

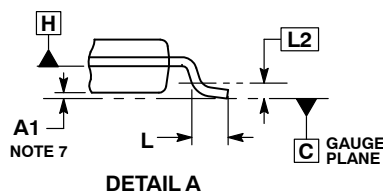
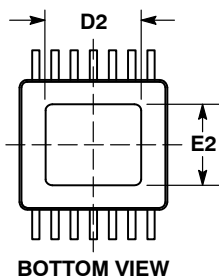


NOTES:

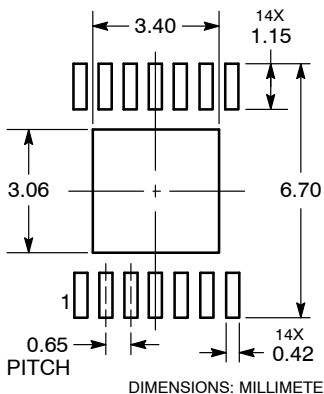
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. DIMENSION b DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE PROTRUSION SHALL BE 0.07 mm MAX. AT MAXIMUM MATERIAL CONDITION. DAMBAR CANNOT BE LOCATED ON THE LOWER RADII OF THE FOOT. MINIMUM SPACE BETWEEN PROTRUSION AND ADJACENT LEAD IS 0.07.
4. DIMENSION D DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH, PROTRUSIONS OR GATE BURRS SHALL NOT EXCEED 0.15 mm PER SIDE. DIMENSION D IS DETERMINED AT DATUM H.
5. DIMENSION E1 DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSIONS. INTERLEAD FLASH OR PROTRUSIONS SHALL NOT EXCEED 0.25 mm PER SIDE. DIMENSION E1 IS DETERMINED AT DATUM H.
6. DATUMS A AND B ARE DETERMINED AT DATUM H.
7. A1 IS DEFINED AS THE VERTICAL DISTANCE FROM THE SEATING PLANE TO THE LOWEST POINT ON THE PACKAGE BODY.
8. SECTION B-B TO BE DETERMINED AT 0.10 TO 0.25 mm FROM THE LEAD TIP.



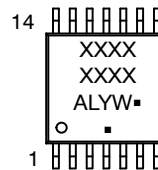
| MILLIMETERS | | |
|-------------|----------|------|
| DIM | MIN | MAX |
| A | --- | 1.20 |
| A1 | 0.05 | 0.15 |
| A2 | 0.80 | 1.05 |
| b | 0.19 | 0.30 |
| b1 | 0.19 | 0.25 |
| c | 0.09 | 0.20 |
| c1 | 0.09 | 0.16 |
| D | 4.90 | 5.10 |
| D2 | 3.09 | 3.62 |
| E | 6.40 BSC | |
| E1 | 4.30 | 4.50 |
| E2 | 2.69 | 3.22 |
| e | 0.65 BSC | |
| L | 0.45 | 0.75 |
| L2 | 0.25 BSC | |
| M | 0° | 8° |



RECOMMENDED SOLDERING FOOTPRINT*



GENERIC MARKING DIAGRAM*



- XXXX = Specific Device Code
- A = Assembly Location
- L = Wafer Lot
- Y = Year
- W = Work Week
- = Pb-Free Package

(Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present.

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

| | | |
|------------------|----------------------|--|
| DOCUMENT NUMBER: | 98AON66474E | Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red. |
| DESCRIPTION: | TSSOP-14 EP, 5.0X4.4 | PAGE 1 OF 1 |

ON Semiconductor and ON are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others.

onsemi, **Onsemi**, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "**onsemi**" or its affiliates and/or subsidiaries in the United States and/or other countries. **onsemi** owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of **onsemi**'s product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. **onsemi** reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and **onsemi** makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does **onsemi** assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using **onsemi** products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by **onsemi**. "Typical" parameters which may be provided in **onsemi** data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. **onsemi** does not convey any license under any of its intellectual property rights nor the rights of others. **onsemi** products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use **onsemi** products for any such unintended or unauthorized application, Buyer shall indemnify and hold **onsemi** and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that **onsemi** was negligent regarding the design or manufacture of the part. **onsemi** is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Email Requests to: orderlit@onsemi.com

onsemi Website: www.onsemi.com

TECHNICAL SUPPORT

North American Technical Support:

Voice Mail: 1 800-282-9855 Toll Free USA/Canada

Phone: 011 421 33 790 2910

Europe, Middle East and Africa Technical Support:

Phone: 00421 33 790 2910

For additional information, please contact your local Sales Representative